NSN 5961-01-302-9814

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-302-9814 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** 0.358 inches **Overall Height:** 0.100 inches **Overall Width:** 0.358 inches **Component Name And Quantity:** 2 semiconductor device diode and 2 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, dc all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Test Data Document:** 04939-717801326 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

20 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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